LM2660 Switched Capacitor Voltage Converter

1 Features

- Inverts or Doubles Input Supply Voltage
- Narrow SOIC and VSSOP Packages
- 6.5-Ω Typical Output Resistance
- 88% Typical Conversion Efficiency at 100 mA
- Selectable Oscillator Frequency: 10 kHz/80 kHz
- Optional External Oscillator Input

2 Applications

- Laptop Computers
- Cellular Phones
- Medical Instruments
- Operational Amplifier Power Supplies
- Interface Power Supplies
- Handheld Instruments

3 Description

The LM2660 CMOS charge-pump voltage converter is a versatile unregulated switched capacitor inverter or doubler. Operating from a wide 1.5-V to 5.5-V supply voltage, the LM2660 uses two low-cost capacitors to provide 100 mA of output current without the cost, size and EMI related to inductor-based converters. With an operating current of only 120 µA and operating efficiency greater than 90% at most loads, the LM2660 provides ideal performance for battery-powered systems. LM2660 devices can be operated directly in parallel to lower output impedance, thus providing more current at a given voltage.

The FC (frequency control) pin selects between a nominal 10-kHz or 80-kHz oscillator frequency. The oscillator frequency can be lowered by adding an external capacitor to the OSC pin. Also, the OSC pin may be used to drive the LM2660 with an external clock up to 150 kHz. Through these methods, output ripple frequency and harmonics may be controlled.

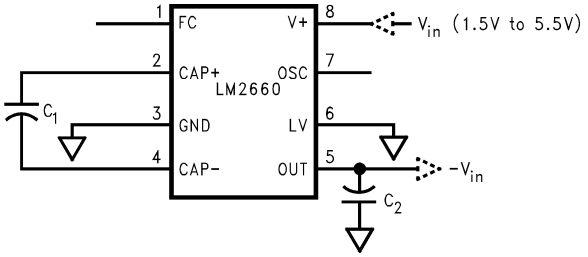
Additionally, the LM2660 may be configured to divide a positive input voltage precisely in half. In this mode, input voltages as high as 11 V may be used.

Device Information(1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LM2660	SOIC (8)	4.90 mm x 3.91 mm
	VSSOP (8)	3.00 mm x 3.00 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Simplified Schematic



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (May 2013) to Revision E — **Page**

- Added *Device Information* and *Handling Rating* tables, *Feature Description*, *Device Functional Modes*, *Application and Implementation*, *Power Supply Recommendations*, *Layout*, *Device and Documentation Support*, and *Mechanical, Packaging, and Orderable Information* sections; moved some curves to *Application Curves* section ... 1

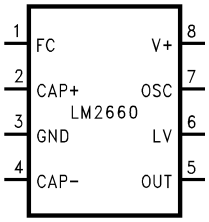
Changes from Revision C (May 2013) to Revision D — **Page**

- Changed layout of National Data Sheet to TI format ... 15

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5 Pin Configuration and Functions

SOIC (D) and VSSOP (DGK)
8 Pins
Top View



Pin Functions

PIN		TYPE	DESCRIPTION	
NUMBER	NAME		VOLTAGE INVERTER	VOLTAGE DOUBLER
1	FC	Input	Frequency control for internal oscillator: FC = open, f_{OSC} = 10 kHz (typ); FC = V+, f_{OSC} = 80 kHz (typ); FC has no effect when OSC pin is driven externally.	Same as inverter.
2	CAP+	Power	Connect this pin to the positive terminal of charge-pump capacitor.	Same as inverter.
3	GND	Ground	Power supply ground input.	Power supply positive voltage input.
4	CAP−	Power	Connect this pin to the negative terminal of charge-pump capacitor.	Same as inverter.
5	OUT	Power	Negative voltage output.	Power supply ground input.
6	LV	Input	Low-voltage operation input. Tie LV to GND when input voltage is less than 3.5 V. Above 3.5 V, LV can be connected to GND or left open. When driving OSC with an external clock, LV must be connected to GND.	LV must be tied to OUT.
7	OSC	Input	Oscillator control input. OSC is connected to an internal 15-pF capacitor. An external capacitor can be connected to slow the oscillator. Also, an external clock can be used to drive OSC.	Same as inverter except that OSC cannot be driven by an external clock.
8	V+	Power	Power supply positive voltage input.	Positive voltage output.

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

	MIN	MAX	UNIT
Supply voltage (V+ to GND, or GND to OUT)		6	V
LV	(OUT − 0.3 V) to (GND + 3 V)		V
FC, OSC	The least negative of (OUT − 0.3 V) or (V+ − 6 V) to (V+ + 0.3 V)		V
V+ and OUT continuous output current		120	mA
Output short-circuit duration to GND (2)		1	second
Power dissipation SOIC (D)(3)		735	mW
Power dissipation VSSOP (DGK)(3)		500	mW
Lead temperature (soldering, 10 seconds)		300	°C
Operating junction temperature	–40	85	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) OUT may be shorted to GND for one second without damage. However, shorting OUT to V+ may damage the device and should be avoided. Also, for temperatures above 85°C, OUT must not be shorted to GND or V+, or device may be damaged.
(3) The maximum allowable power dissipation is calculated by using $P_{DMax} = (T_{JMax} - T_A)/R_{\theta JA}$, where T_{JMax} is the maximum junction temperature, T_A is the ambient temperature, and $R_{\theta JA}$ is the junction-to-ambient thermal resistance of the specified package.

6.2 Handling Ratings

			MIN	MAX	UNIT
T_{stg}	Storage temperature range		–65	150	°C
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins(1)		2000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V+ (supply voltage)	Inverter, LV = Open	3.5		5.5	
	Inverter, LV = GND	1.5		5.5	
	Doubler, LV = OUT	2.5		5.5	
Junction temperature (T_J)		–40		85	°C

6.4 Thermal Information

THERMAL METRIC(1)		LM2660		UNIT
		SOIC (D)	VSSOP (DGK)	
		8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	170	250	°C/W

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.

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6.5 Electrical Characteristics

Limits in for typical (TYP) values are for T_J = 25°C, and limits in for minimum (MIN) and maximum (MAX) values apply over the full operating temperature range; V+ = 5V, FC = Open, $C_1 = C_2$ = 150 µF, unless otherwise specified in the Test Conditions.(1)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V+	Supply voltage	R_L = 1k	Inverter, LV = Open	3.5		5.5	V
			Inverter, LV = GND	1.5		5.5	
			Doubler, LV = OUT	2.5		5.5	
I_Q	Supply current	No Load	FC = Open		0.12	0.5	mA
		LV = Open	FC = V+		1	3	
I_L	Output current	$T_A \le 85°C$, OUT ≤ −4 V		100			mA
		$T_A > 85°C$, OUT ≤ −3.8 V		100			
R_{OUT}	Output resistance(2)	I_L = 100 mA	$T_A \le 85°C$		6.5	10	Ω
			$T_A > 85°C$			12	
f_{OSC}	Oscillator frequency	OSC = Open	FC = Open	5	10		kHz
			FC = V+	40	80		
f_{SW}	Switching frequency(3)	OSC = Open	FC = Open	2.5	5		kHz
			FC = V+	20	40		
I_{OSC}	OSC input current	FC = Open			±2		µA
		FC = V+			±16		
P_{EFF}	Power efficiency	R_L (1k) between V^+ and OUT		96%	98%		
		R_L (500) between GND and OUT		92%	96%		
		I_L = 100 mA to GND			88%		
V_{OEFF}	Voltage conversion efficiency	No Load		99%	99.96%		

(1) In the test circuit, capacitors C_1 and C_2 are 0.2-Ω maximum ESR capacitors. Capacitors with higher ESR will increase output resistance, reduce output voltage and efficiency.
(2) Specified output resistance includes internal switch resistance and capacitor ESR.
(3) The output switches operate at one half of the oscillator frequency, $f_{OSC} = 2f_{SW}$.

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6.6 Typical Characteristics

(Circuit of Figure 12)

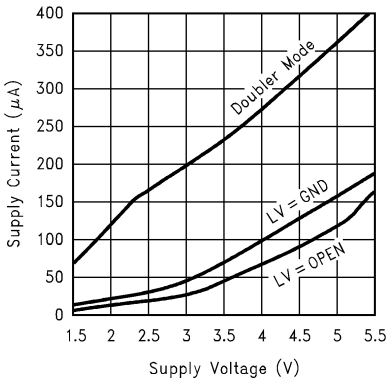


Figure 1. Supply Current vs Supply Voltage

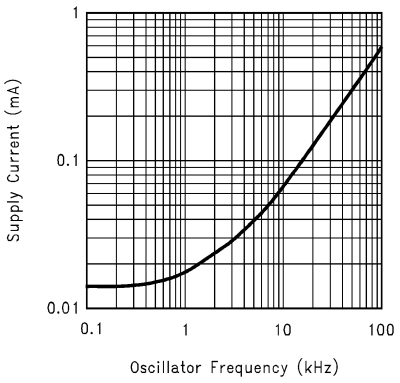


Figure 2. Supply Current vs Oscillator Frequency

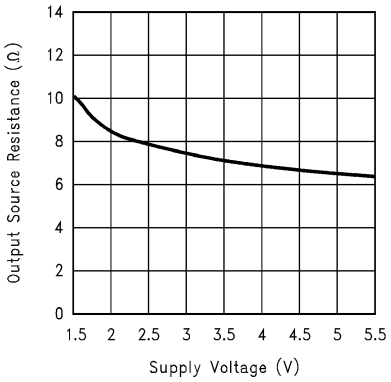


Figure 3. Output Source Resistance vs Supply Voltage

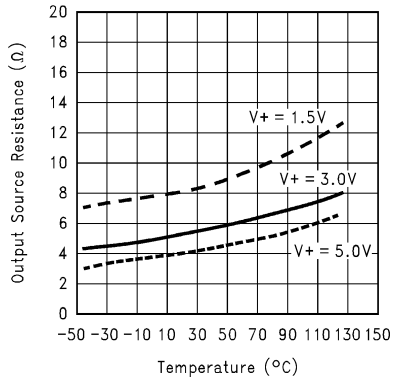


Figure 4. Output Source Resistance vs Temperature

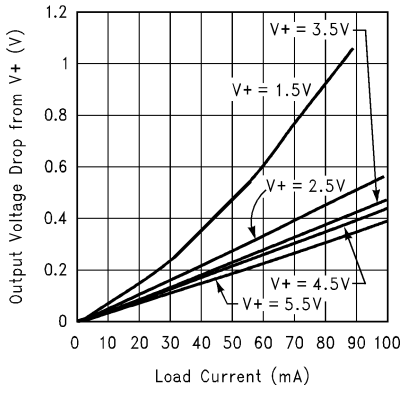


Figure 5. Output Voltage Drop vs Load Current

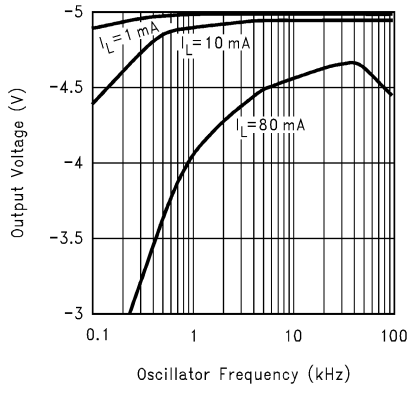


Figure 6. Output Voltage vs Oscillator Frequency

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Typical Characteristics (continued)

(Circuit of Figure 12)

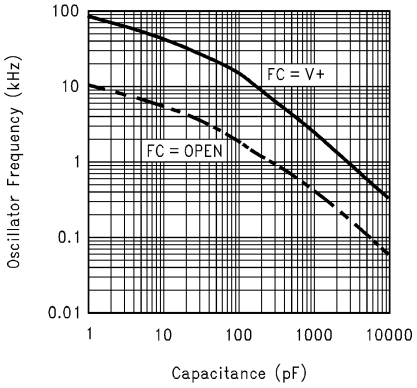


Figure 7. Oscillator Frequency vs External Capacitance

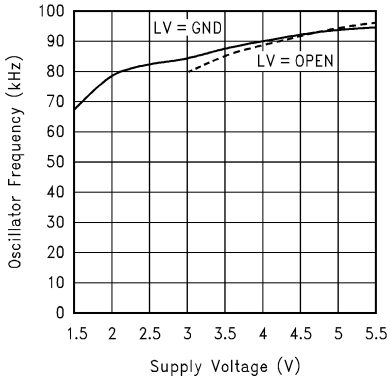


Figure 8. Oscillator Frequency vs Supply Voltage (Fc = V+)

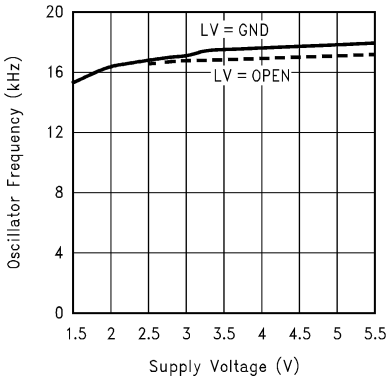


Figure 9. Oscillator Frequency vs Supply Voltage (Fc = Open)

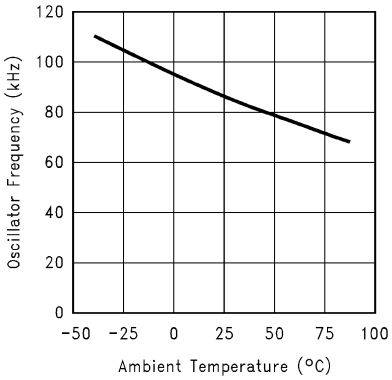


Figure 10. Oscillator Frequency vs Temperature (Fc = V+)

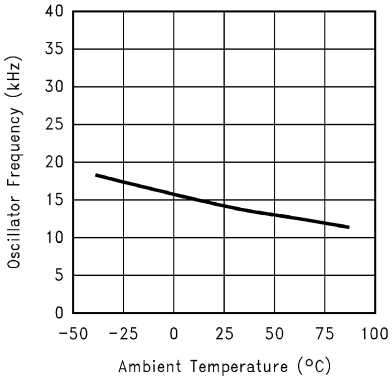


Figure 11. Oscillator Frequency vs Temperature (Fc = Open)

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7 Parameter Measurement Information

7.1 Test Circuits

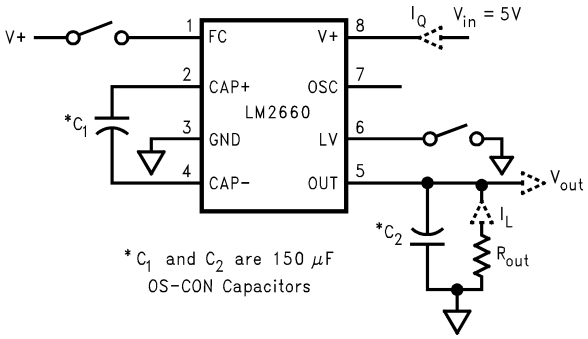


Figure 12. LM2660 Test Circuit

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8 Detailed Description

8.1 Overview

The LM2660 contains four large CMOS switches which are switched in a sequence to invert the input supply voltage. Energy transfer and storage are provided by external capacitors. Figure 13 illustrates the voltage conversion scheme. When S_1 and S_3 are closed, C_1 charges to the supply voltage V+. During this time interval switches S_2 and S_4 are open. In the second time interval, S_1 and S_3 are open and S_2 and S_4 are closed, C_1 is charging C_2. After a number of cycles, the voltage across C_2 will be pumped to V+. Since the anode of C_2 is connected to ground, the output at the cathode of C_2 equals −(V+) assuming no load on C_2, no loss in the switches, and no ESR in the capacitors. In reality, the charge transfer efficiency depends on the switching frequency, the on-resistance of the switches, and the ESR of the capacitors.

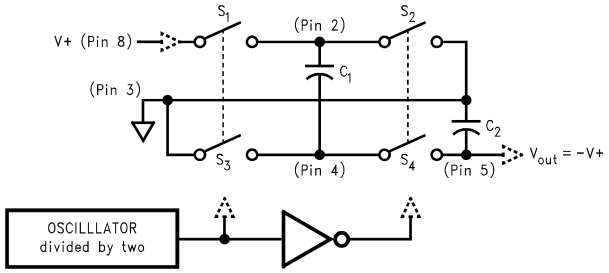
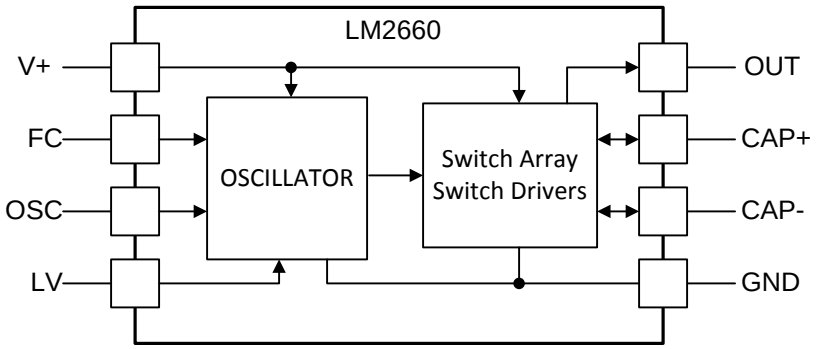


Figure 13. Voltage Inverting Principle

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Changing Oscillator Frequency

The internal oscillator frequency can be selected using the Frequency Control (FC) pin. When FC is open, the oscillator frequency is 10 kHz; when FC is connected to V+, the frequency increases to 80 kHz. A higher oscillator frequency allows smaller capacitors to be used for equivalent output resistance and ripple, but increases the typical supply current from 0.12 mA to 1 mA.

The oscillator frequency can be lowered by adding an external capacitor between OSC and GND. (See *Typical Characteristics*.) Also, in the inverter mode, an external clock that swings within 100 mV of V+ and GND can be used to drive OSC. Any CMOS logic gate is suitable for driving OSC. LV must be grounded when driving OSC. The maximum external clock frequency is limited to 150 kHz.

The switching frequency of the converter (also called the charge pump frequency) is half of the oscillator frequency.

NOTE

OSC cannot be driven by an external clock in the voltage-doubling mode.

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Feature Description (continued)

Table 1. LM2660 Oscillator Frequency Selection

FC	OSC	OSCILLATOR
Open	Open	10 kHz
V+	Open	80 kHz
Open or V+	External Capacitor	See *Typical Characteristics*
N/A	External Clock	External Clock
	(inverter mode only)	Frequency

8.4 Device Functional Modes

When V+ is applied to the LM2660, the device becomes enabled and will operate in which ever configuration the device is placed (inverter, doubler, etc.).

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9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The LM2660 CMOS charge-pump voltage converter is a versatile unregulated switched capacitor inverter or doubler. Operating from a wide 1.5 V to 5.5 V supply voltage, the LM2660 uses two low-cost capacitors to provide 100 mA of output current without the cost, size and EMI related to inductor-based converters. With an operating current of only 120 µA and operating efficiency greater than 90% at most loads, the LM2660 provides ideal performance for battery-powered systems. LM2660 devices can be operated directly in parallel to lower output impedance, thus providing more current at a given voltage.

9.2 Typical Applications

9.2.1 Voltage Inverter

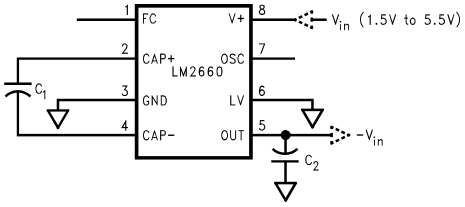


Figure 14. LM2660 Voltage Inverter

9.2.1.1 Design Requirements

The main application of LM2660 is to generate a negative supply voltage. The voltage inverter circuit uses only two external capacitors as shown in the Figure 14. The range of the input supply voltage is 1.5 V to 5.5 V. For a supply voltage less than 3.5V, the LV pin must be connected to ground to bypass the internal regulator circuitry. This gives the best performance in low voltage applications. If the supply voltage is greater than 3.5 V, LV may be connected to ground or left open. The choice of leaving LV open simplifies the direct substitution of the LM2660 for the LMC7660 Switched Capacitor Voltage Converter.

9.2.1.2 Detailed Design Procedure

The output characteristics of this circuit can be approximated by an ideal voltage source in series with a resistor. The voltage source equals −(V+). The output resistance R_{out} is a function of the ON resistance of the internal MOS switches, the oscillator frequency, and the capacitance and ESR of C_1 and C_2. A good approximation is:

$$R_{out} \cong 2R_{SW} + \frac{2}{f_{osc} \times C_1} + 4\,ESR_{C1} + ESR_{C2} \quad (1)$$

where

- R_{SW} is the sum of the ON resistance of the internal MOS switches shown in Figure 13.

High value, low ESR capacitors will reduce the output resistance. Instead of increasing the capacitance, the oscillator frequency can be increased to reduce the $2/(f_{osc} \times C_1)$ term. Once this term is trivial compared with R_{SW} and ESRs, further increasing in oscillator frequency and capacitance will become ineffective.

The peak-to-peak output voltage ripple is determined by the oscillator frequency, and the capacitance and ESR of the output capacitor C_2:

$$V_{ripple} = \frac{I_L}{f_{osc} \times C_2} + 2 \times I_L \times ESR_{C2} \quad (2)$$

Again, using a low ESR capacitor will result in lower ripple.

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Typical Applications (continued)

9.2.1.2.1 Capacitor Selection

The output resistance and ripple voltage are dependent on the capacitance and ESR values of the external capacitors. The output voltage drop is the load current times the output resistance, and the power efficiency is

$$\eta = \frac{P_{out}}{P_{in}} = \frac{I_L^2 R_L}{I_L^2 R_L + I_L^2 R_{out} + I_Q (V+)} \quad (3)$$

where

- $I_Q(V+)$ is the quiescent power loss of the IC device, and
- $I_L^2 R_{OUT}$ is the conversion loss associated with the switch on-resistance, the two external capacitors and their ESRs.

Since the switching current charging and discharging C_1 is approximately twice as the output current, the effect of the ESR of the pumping capacitor C_1 is multiplied by four in the output resistance. The output capacitor C_2 is charging and discharging at a current approximately equal to the output current, therefore, its ESR only counts once in the output resistance. However, the ESR of C_2 directly affects the output voltage ripple. Therefore, low ESR capacitors (Table 2) are recommended for both capacitors to maximize efficiency, reduce the output voltage drop and voltage ripple. For convenience, C_1 and C_2 are usually chosen to be the same.

The output resistance varies with the oscillator frequency and the capacitors. In Figure 15, the output resistance vs. oscillator frequency curves are drawn for three different tantalum capacitors. At very low frequency range, capacitance plays the most important role in determining the output resistance. Once the frequency is increased to some point (such as 20 kHz for the 150 µF capacitors), the output resistance is dominated by the ON resistance of the internal switches and the ESRs of the external capacitors. A low value, smaller size capacitor usually has a higher ESR compared with a bigger size capacitor of the same type. For lower ESR, use ceramic capacitors.

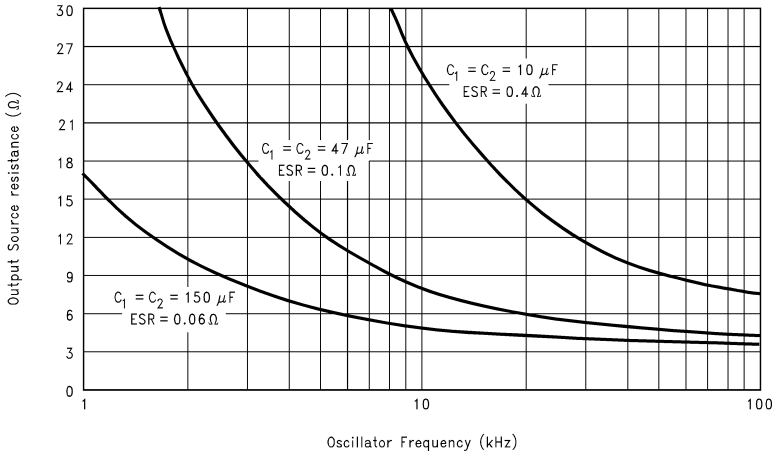


Figure 15. Output Source Resistance vs Oscillator Frequency

Table 2. Low ESR Capacitor Manufacturers

MANUFACTURER	CAPACITOR TYPE
Nichicon Corp.	PL, PF series, through-hole aluminum electrolytic
AVX Corp.	TPS series, surface-mount tantalum
Sprague	593D, 594D, 595D series, surface-mount tantalum
Sanyo	OS-CON series, through-hole aluminum electrolytic

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9.2.1.2.2 Paralleling Devices

Any number of LM2660s can be paralleled to reduce the output resistance. Each device must have its own pumping capacitor C_1, while only one output capacitor C_{out} is needed as shown in Figure 16. The composite output resistance is:

$$R_{out} = \frac{R_{out} \text{ of each LM2660}}{\text{Number of Devices}} \tag{4}$$

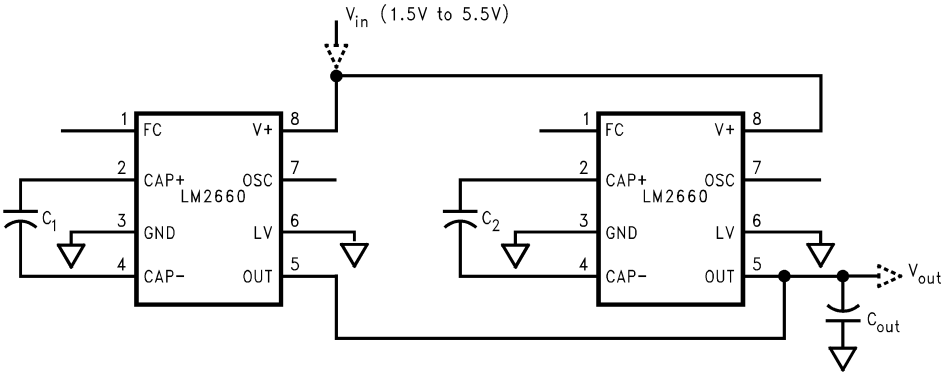


Figure 16. Lowering Output Resistance By Paralleling Devices

9.2.1.2.3 Cascading Devices

Cascading the LM2660s is an easy way to produce a greater negative voltage (as shown in Figure 17). If n is the integer representing the number of devices cascaded, the unloaded output voltage V_{out} is ($-nV_{in}$). The effective output resistance is equal to the weighted sum of each individual device:

$$R_{out} = nR_{out_1} + \frac{n}{2}R_{out_2} + \ldots + R_{out_n} \tag{5}$$

A three-stage cascade circuit shown in Figure 18 generates $-3\ V_{in}$, from V_{in}.

Cascading is also possible when devices are operating in doubling mode. In Figure 19, two devices are cascaded to generate $3\ V_{in}$.

An example of using the circuit in Figure 18 or Figure 19 is generating +15 V or −15 V from a +5 V input.

Note that, the number of n is practically limited since the increasing of n significantly reduces the efficiency and increases the output resistance and output voltage ripple.

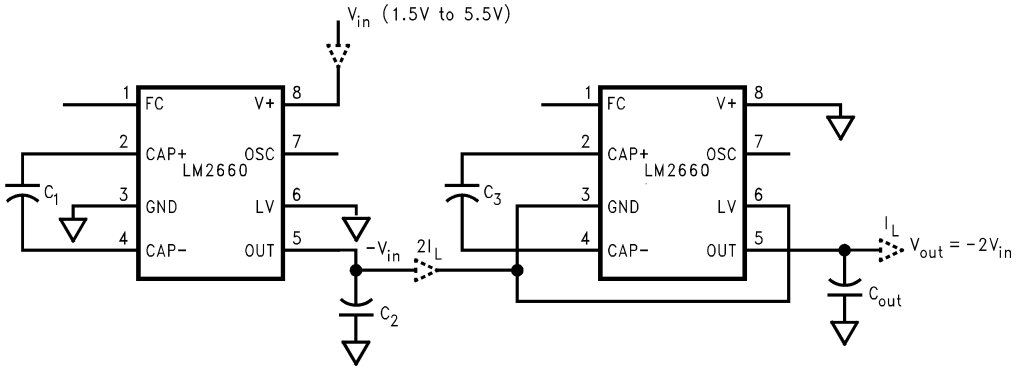


Figure 17. Increasing Output Voltage by Cascading Devices

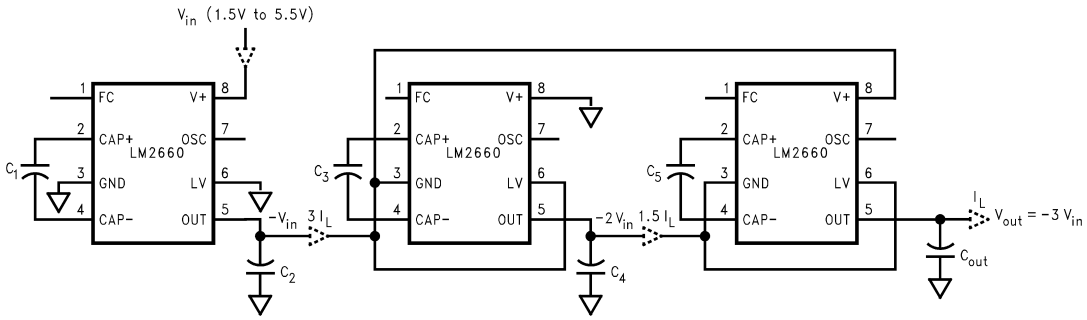


Figure 18. Generating −3V$_{IN}$ from +V$_{IN}$

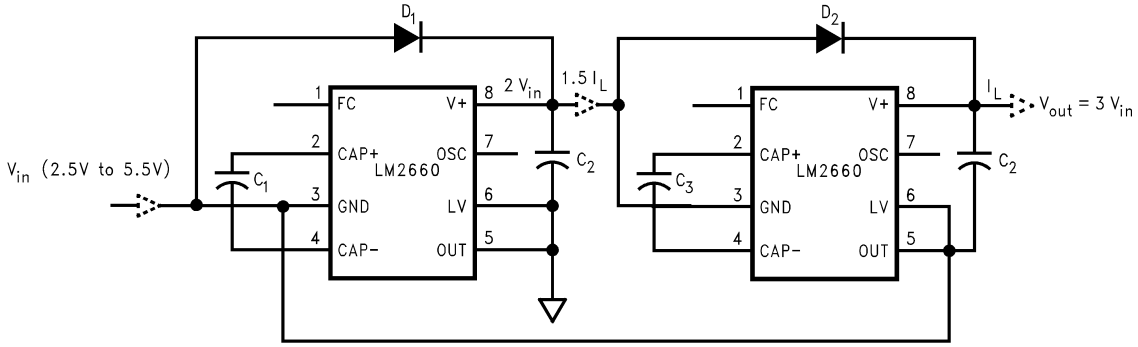


Figure 19. Generating +3V$_{IN}$ from +V$_{IN}$

9.2.1.2.4 Regulating V_{OUT}

It is possible to regulate the output of the LM2660 by use of a low dropout regulator (such as LP2951). The whole converter is depicted in Figure 20. This converter can give a regulated output from −1.5 V to −5.5 V by choosing the proper resistor ratio:

$$V_{out} = V_{ref}\left(1 + \frac{R_1}{R_2}\right) \quad (6)$$

where

- V_{ref} = 1.235 V

The error flag on pin 5 of the LP2951 goes low when the regulated output at pin 4 drops by about 5%. The LP2951 can be shutdown by taking pin 3 high.

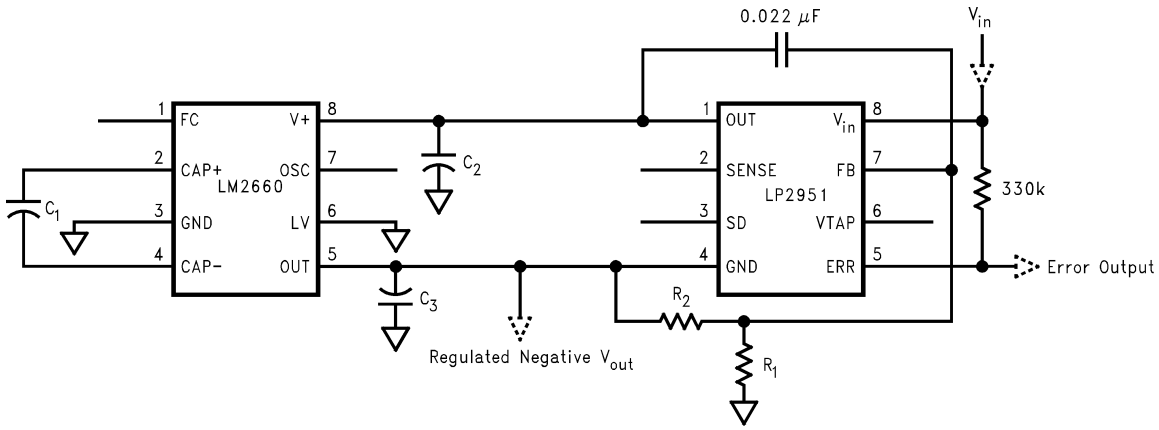


Figure 20. Combining LM2660 With LP2951 to Make a Negative Adjustable Regulator

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Also, as shown in Figure 21 by operating LM2660 in voltage doubling mode and adding a linear regulator (such as LP2981) at the output, we can get +5 V output from an input as low as +3 V.

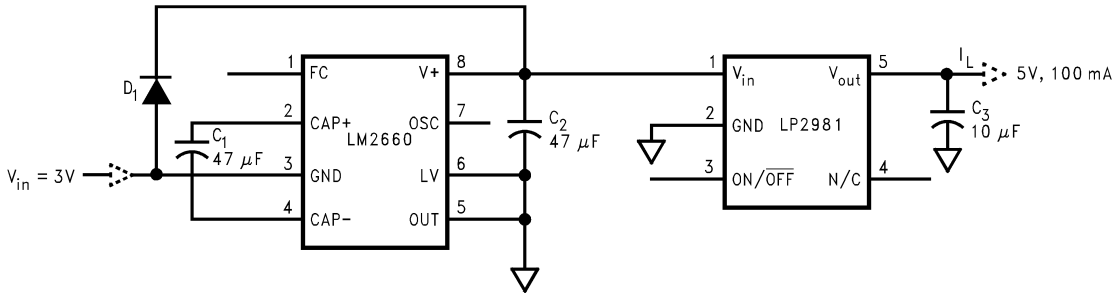


Figure 21. Generating +5 V from +3 V Input Voltage

9.2.1.3 Application Curves

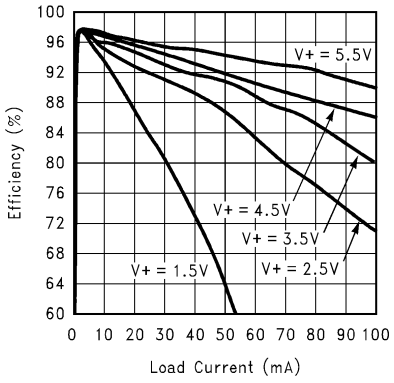


Figure 22. Efficiency vs Load Current

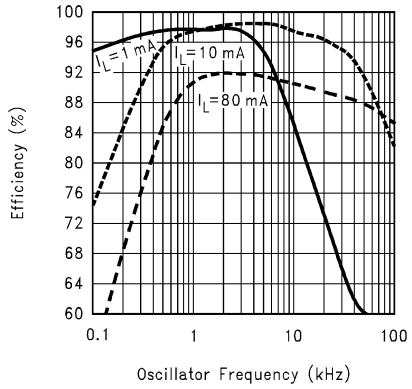


Figure 23. Efficiency vs Oscillator Frequency

9.2.2 Positive Voltage Doubler

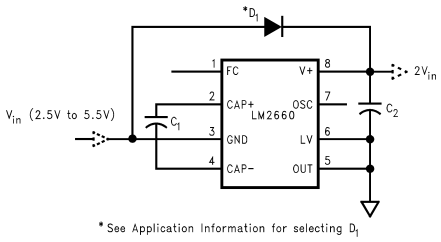


Figure 24. LM2660 Voltage Doubler

9.2.2.1 Design Requirements

The LM2660 can operate as a positive voltage doubler (as shown in the Figure 24). The doubling function is achieved by reversing some of the connections to the device. The input voltage is applied to the GND pin with an allowable voltage from 2.5 V to 5.5 V. The V+ pin is used as the output. The LV pin and OUT pin must be connected to ground. The OSC pin can not be driven by an external clock in this operation mode. The unloaded output voltage is twice of the input voltage and is not reduced by the diode D_1's forward drop.

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9.2.2.2 Detailed Design Procedure

The Schottky diode D_1 is only needed for start-up. The internal oscillator circuit uses the V+ pin and the LV pin (connected to ground in the voltage doubler circuit) as its power rails. Voltage across V+ and LV must be larger than 1.5 V to insure the operation of the oscillator. During start-up, D_1 is used to charge up the voltage at V+ pin to start the oscillator; also, it protects the device from turning-on its own parasitic diode and potentially latching-up. Therefore, the Schottky diode D_1 should have enough current carrying capability to charge the output capacitor at start-up, as well as a low forward voltage to prevent the internal parasitic diode from turning-on. A Schottky diode like 1N5817 can be used for most applications. If the input voltage ramp is less than 10V/ms, a smaller Schottky diode like MBR0520LT1 can be used to reduce the circuit size.

9.2.2.3 Application Curves

See *Application Curves* in the *Voltage Inverter* section.

10 Power Supply Recommendations

The LM2660 is designed to operate from as an inverter over an input voltage supply range between 1.5 V and 5.5 V when the LV pin is grounded. This input supply must be well regulated and capable to supply the required input current. If the input supply is located far from the LM2660 additional bulk capacitance may be required in addition to the ceramic bypass capacitors.

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11 Layout

11.1 Layout Guidelines

The high switching frequency and large switching currents of the LM2660 make the choice of layout important. The following steps should be used as a reference to ensure the device is stable and maintains proper LED current regulation across its intended operating voltage and current range:

- Place C_{IN} on the top layer (same layer as the LM2660) and as close to the device as possible. Connecting the input capacitor through short, wide traces to both the V+ and GND pins reduces the inductive voltage spikes that occur during switching which can corrupt the V+ line.
- Place C_{OUT} on the top layer (same layer as the LM2660) and as close as possible to the OUT and GND pin. The returns for both C_{IN} and C_{OUT} should come together at one point, as close to the GND pin as possible. Connecting C_{OUT} through short, wide traces reduce the series inductance on the OUT and GND pins that can corrupt the V_{OUT} and GND lines and cause excessive noise in the device and surrounding circuitry.
- Place C_1 on the top layer (same layer as the LM2660) and as close to the device as possible. Connect the flying capacitor through short, wide traces to both the CAP+ and CAP– pins.

11.2 Layout Example

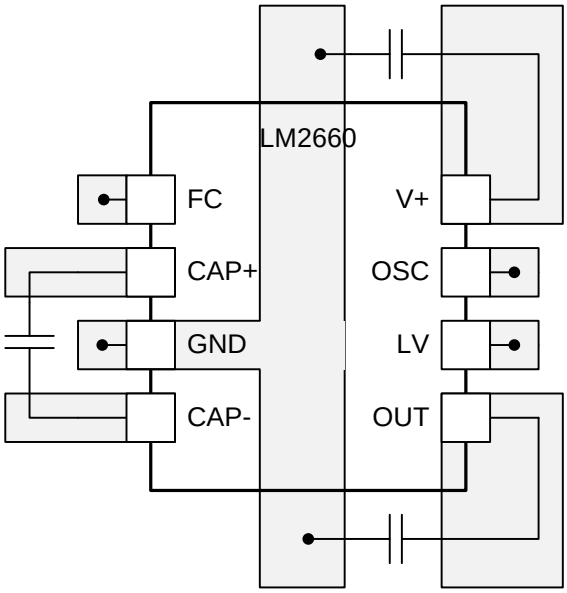


Figure 25. LM2660 Layout Example

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12 Device and Documentation Support

12.1 Device Support

12.1.1 Third-Party Products Disclaimer

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12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

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13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM2660-MWC	Active	Production	WAFERSALE (YS) | 0	1 | NOT REQUIRED	-	Call TI	Level-1-NA-UNLIM	-40 to 85	
LM2660-MWC.A	Active	Production	WAFERSALE (YS) | 0	1 | NOT REQUIRED	-	Call TI	Level-1-NA-UNLIM	-40 to 85	
LM2660M/NOPB	Active	Production	SOIC (D) | 8	95 | TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM26 60M
LM2660M/NOPB.A	Active	Production	SOIC (D) | 8	95 | TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM26 60M
LM2660M/NOPB.B	Active	Production	SOIC (D) | 8	95 | TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM26 60M
LM2660MM/NOPB	Active	Production	VSSOP (DGK) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	S01A
LM2660MM/NOPB.A	Active	Production	VSSOP (DGK) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	S01A
LM2660MM/NOPB.B	Active	Production	VSSOP (DGK) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	S01A
LM2660MX/NOPB	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM26 60M
LM2660MX/NOPB.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM26 60M
LM2660MX/NOPB.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM26 60M

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

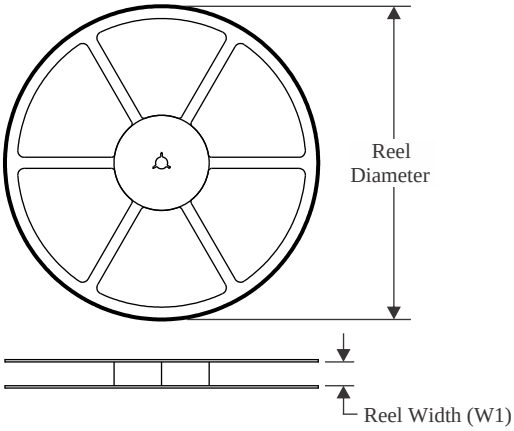
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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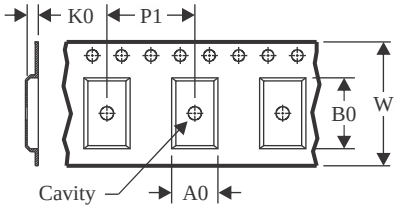
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TAPE AND REEL INFORMATION

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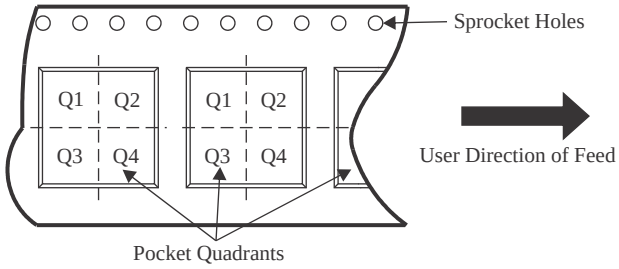


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

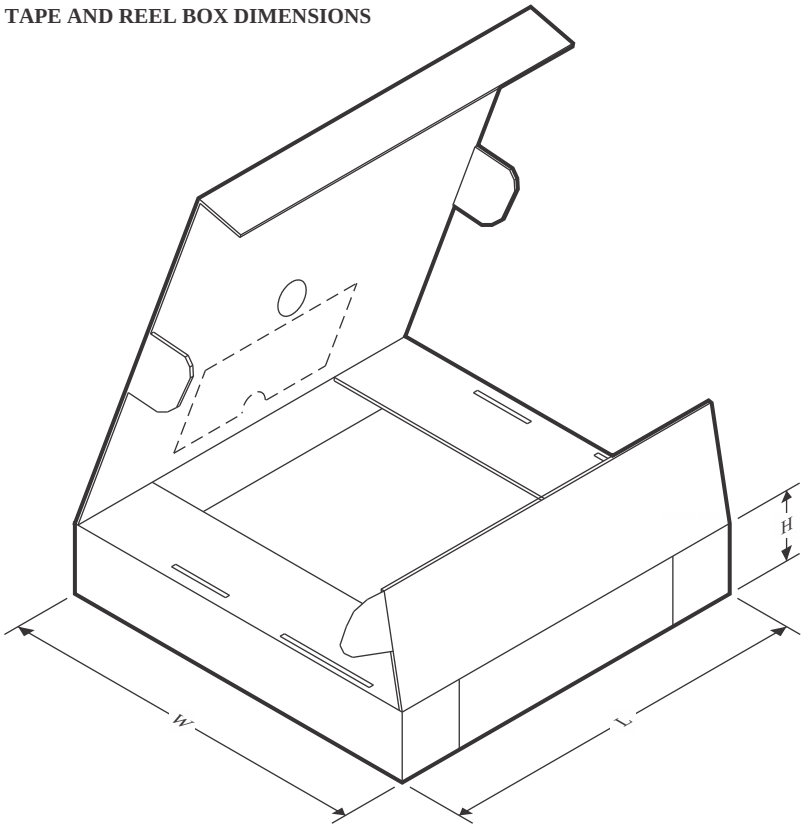
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2660MM/NOPB	VSSOP	DGK	8	1000	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM2660MX/NOPB	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

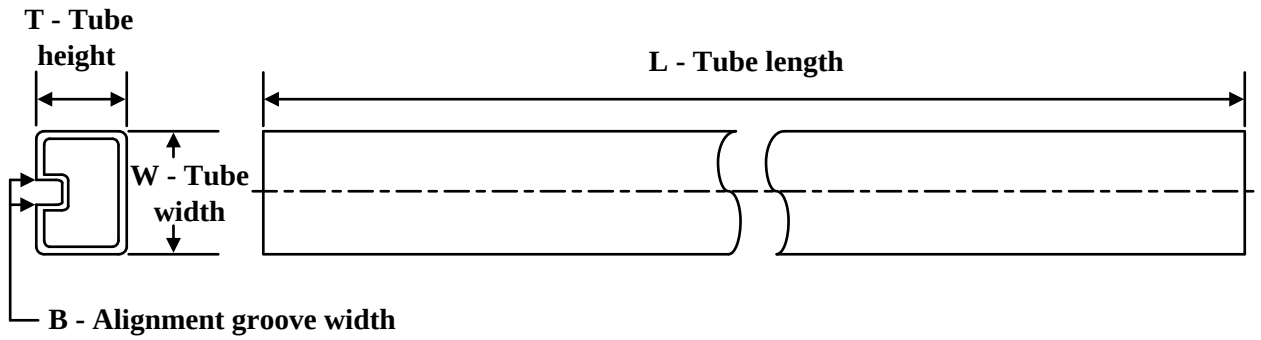
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

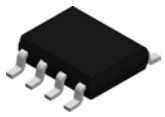
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2660MM/NOPB	VSSOP	DGK	8	1000	210.0	185.0	35.0
LM2660MX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LM2660M/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM2660M/NOPB.A	D	SOIC	8	95	495	8	4064	3.05
LM2660M/NOPB.B	D	SOIC	8	95	495	8	4064	3.05

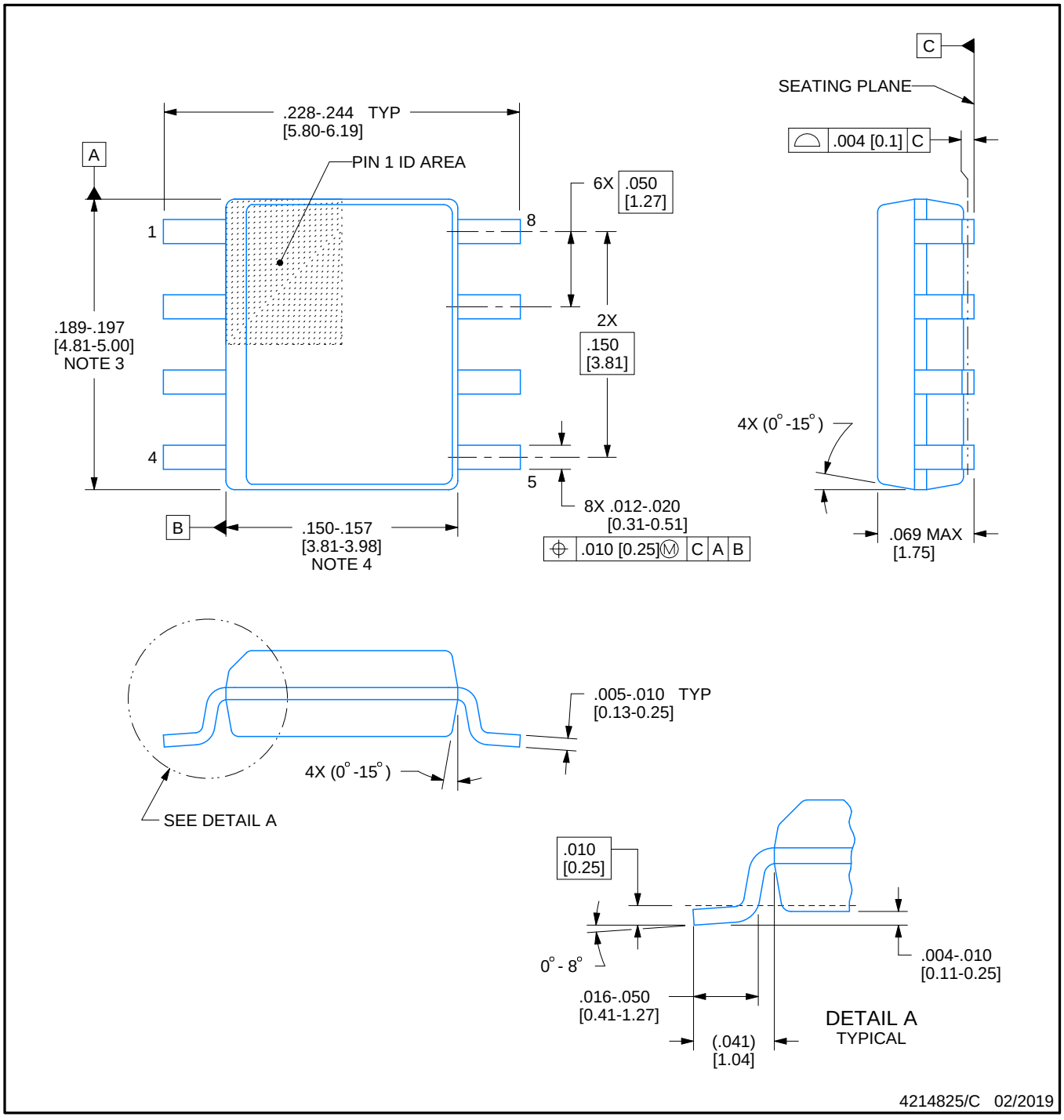


PACKAGE OUTLINE

D0008A

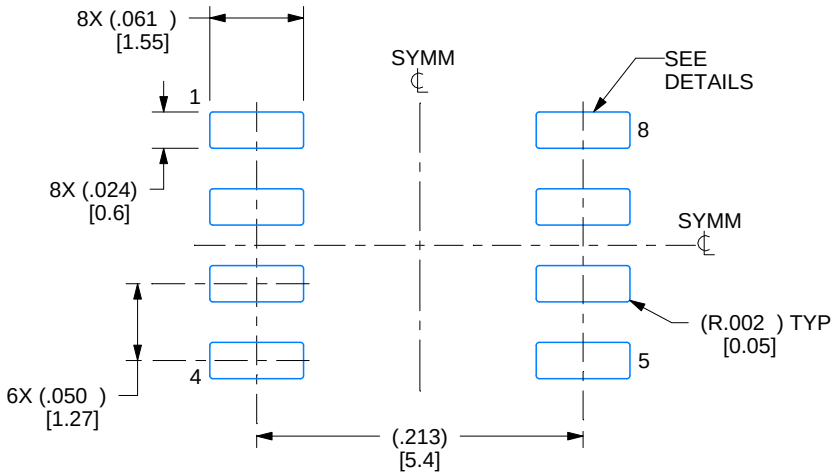
SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

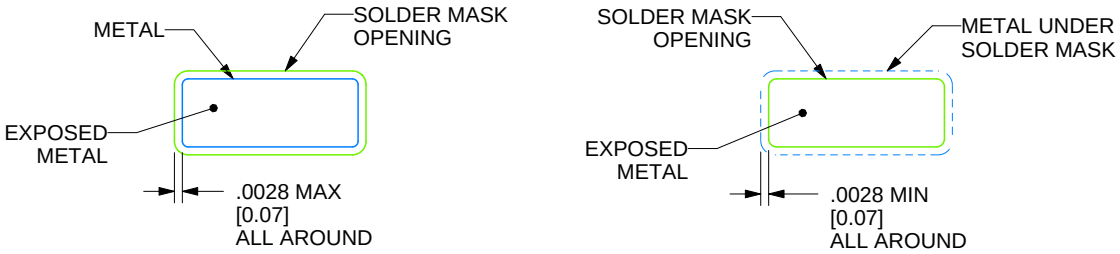


NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

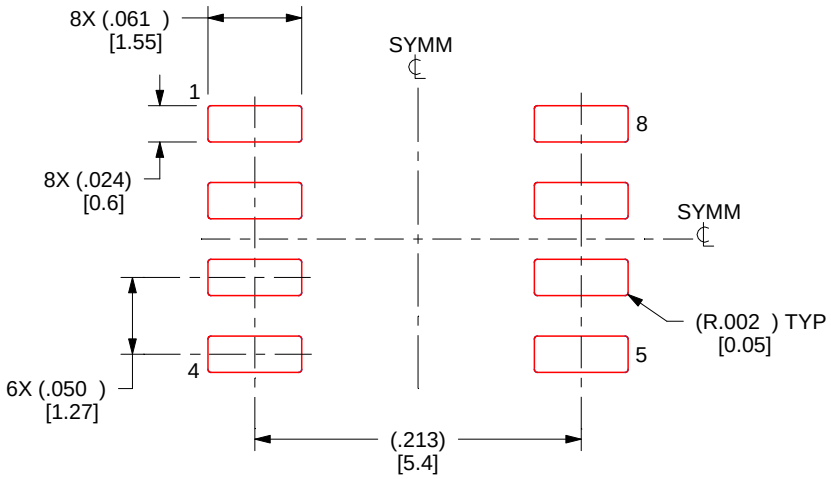
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

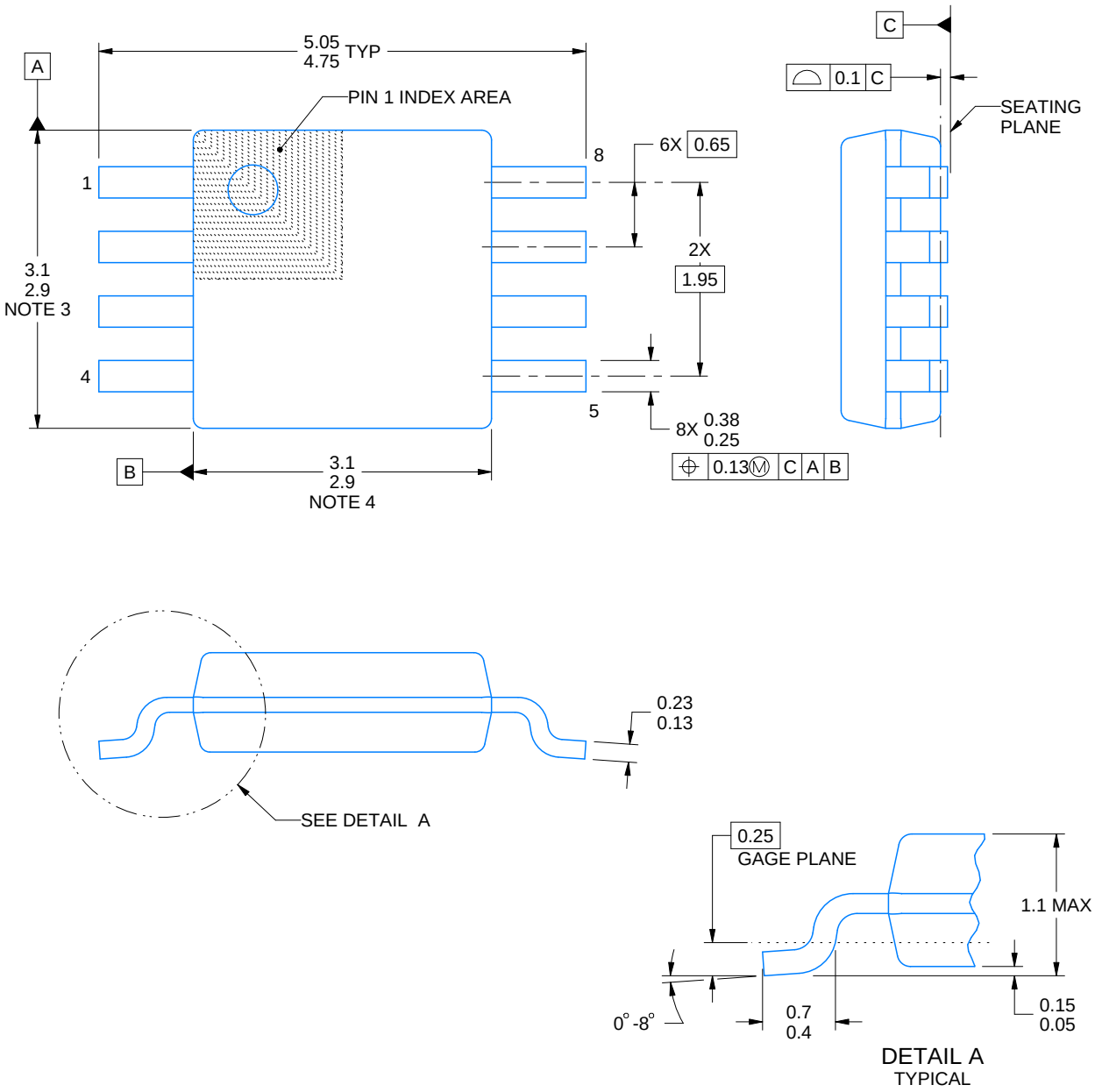
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

DGK0008A

VSSOP - 1.1 mm max height

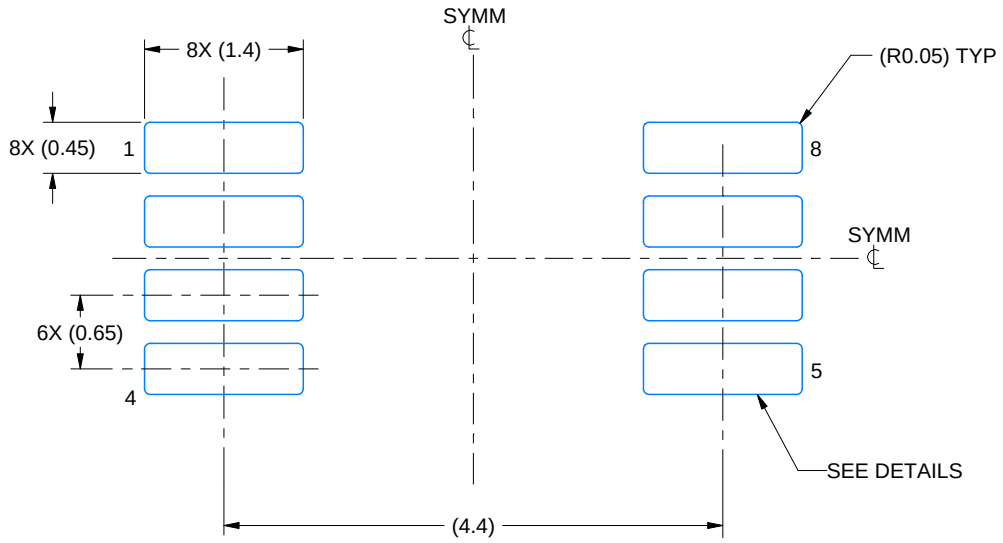
SMALL OUTLINE PACKAGE



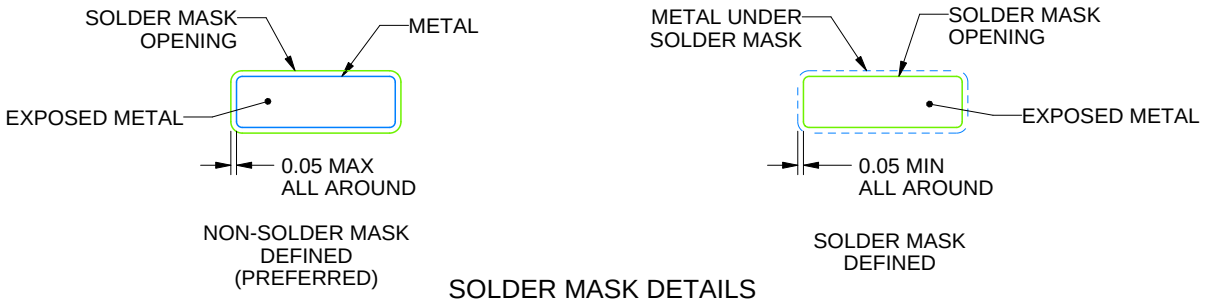
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LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

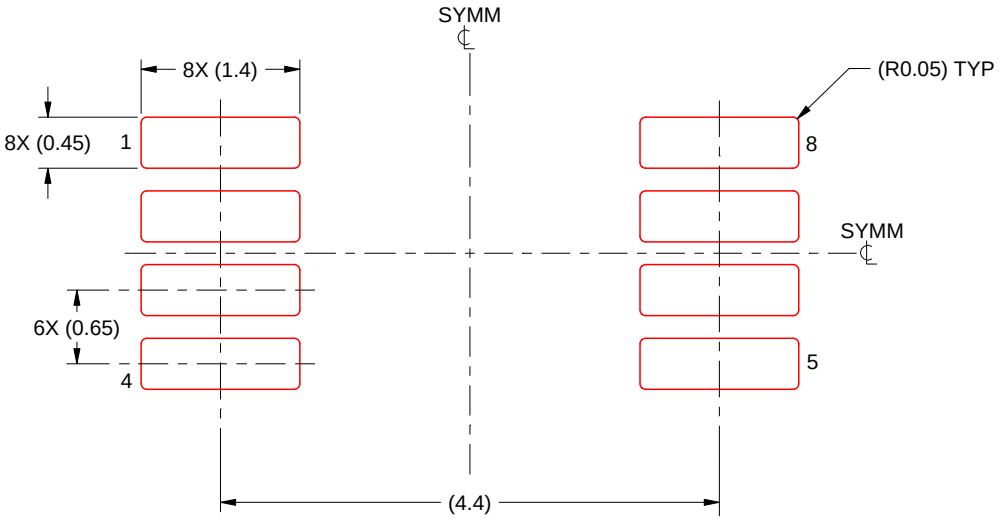


SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

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12. Board assembly site may have different recommendations for stencil design.

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